NSN 5961-01-272-8946



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-272-8946 **Inclosure Material:** Ceramic **Overall Length:** 0.595 inches **Overall Height:** 0.575 inches **Overall Width:** 0.575 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 800.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 16.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** The ceramic bodies of these devices contain beryllium oxide; junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: